

1.3 mm WDM PIN PHOTODIODES

PD-3100 SERIES

FEATURES

- 2 High responsivity at 1310 nm
- 2 High attenuation at 1550 nm
- 2 Low dark current
- 2 Quick pulse response
- 2 Hermetically sealed 3-pin metal case
- 2 Active diameter 75 μm

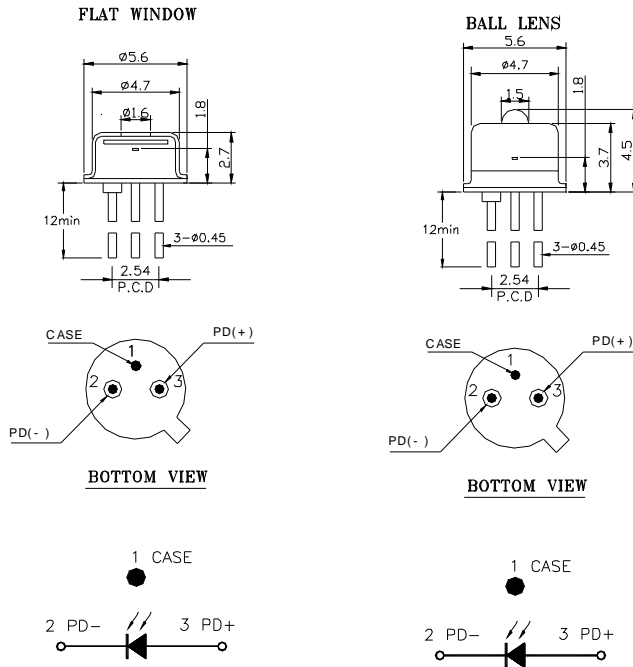
DESCRIPTION

PD-3100 series InGaAsP Photodiode are suited to receive the light at the wavelength 1310 nm. With high reliability and high isolation between 1310 nm and 1550 nm (at least 30 dB), PD-3100 series are the best choice for 1310 nm / 1550 nm WDM telecom and datacom application.

ELECTRICAL AND OPTICAL CHARACTERISTICS ($T_C=25^\circ\text{C}$)						
Symbol	Parameter	Test Conditions	Min.	Typ.	Max.	Unit
	Active Area			75		μm
	Detection Range		1260	1310	1360	nm
R	Responsivity	$V_R=5V, \lambda=1300\text{nm}$ $\lambda=1550\text{nm}$	0.8		- 0.005	A/W
I_{dark}	Dark Current	$V_R=5V$		0.3	0.7	nA
C	Capacitance	$V_R=5V$		0.7	0.9	pF
T_r/T_f	Rise/Fall Time	$V_R=5V, 10\sim90\%$			0.3	ns
BW	Bandwidth	$V_R=5V$	2			GHz

ABSOLUTE MAXIMUM RATINGS ($T_C=25^\circ\text{C}$)			
Symbol	Parameter	Ratings	Unit
P_o	Input Optical Power	10	mW
V_{RD}	Reverse Voltage	20	V
I_{FD}	Forward Current	10	mA
T_{opr}	Operating Temperature	-40~+85	$^\circ\text{C}$
T_{stg}	Storage Temperature	-40~+85	$^\circ\text{C}$

MECHANICAL DIMENSION (mm) and PIN ASSIGNMENT



Note: 1. Specifications subject to change without notice.
 2. Other PIN assignment is available upon request.

ORDER INFORMATION

Part No.: P D - 3 1 □ □

Code	Wavelength
1	1310 / 1550 nm
3	1310 nm
5	1550 nm

Code	Diameter
0	75 μm

Code	Package
0	Ball Lens Cap
5	Flat Window Cap